

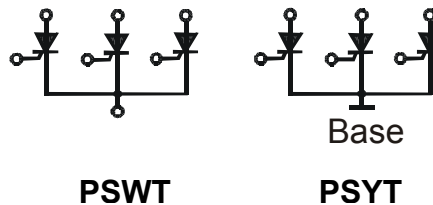
## Thyristor Modules

**PSWT 160**  
**PSYT 160**

$I_{TRMS} = 180 \text{ A}$   
 $V_{RRM} = 800 - 1600 \text{ V}$

### Preliminary Data Sheet

$V_{RSM}$ $V_{DSM}$	$V_{RRM}$ $V_{DRM}$	Type	Type
900	800	PSWT 160/08	PSYT 160/08
1300	1200	PSWT 160/12	PSYT 160/12
1500	1400	PSWT 160/14	PSYT 160/14
1700	1600	PSWT 160/16	PSYT 160/16



Symbol	Test Conditions	Maximum Ratings
$I_{TRMS}$		180      A
$I_{TAVM}$	$T_C = 63^\circ\text{C}$	180° sine, 115      A
$I_{TAVM}$	$T_C = 85^\circ\text{C}$	180° sine, 85      A
$I_{TSM}$	$T_{VJ} = 45^\circ\text{C}$	$t = 10 \text{ ms}$ (50Hz), sine 1700      A
	$V_R = 0$	$t = 8.3 \text{ ms}$ (60Hz), sine 1800      A
	$T_{VJ} = T_{VJM}$	$t = 10 \text{ ms}$ (50Hz), sine 1540      A
	$V_R = 0$	$t = 8.3 \text{ ms}$ (60Hz), sine 1640      A
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}$	$t = 10 \text{ ms}$ (50Hz), sine 14450      A <sup>2</sup> s
	$V_R = 0$	$t = 8.3 \text{ ms}$ (60Hz), sine 13500      A <sup>2</sup> s
	$T_{VJ} = T_{VJM}$	$t = 10 \text{ ms}$ (50Hz), sine 11850      A <sup>2</sup> s
	$V_R = 0$	$t = 8.3 \text{ ms}$ (60Hz), sine 11300      A <sup>2</sup> s
$(di/dt)_{cr}$	$T_{VJ} = T_{VJM}$	repetitive, $I_T = 250 \text{ A}$ 150      A/ $\mu\text{s}$
	$f = 50\text{Hz}$ , $t_p = 200\mu\text{s}$	
	$V_D = 2/3 V_{DRM}$	
	$I_G = 0.45 \text{ A}$	non repetitive; $I_T = I_{TAVM}$ 500      A/ $\mu\text{s}$
	$di_G / dt = 0.45 \text{ A}/\mu\text{s}$	
$(dv/dt)_{cr}$	$T_{VJ} = T_{VJM}$ ;	$V_{DR} = 2/3 V_{DRM}$ 1000      V/ $\mu\text{s}$
	$R_{GK} = \infty$ ; method 1 (linear voltage rise)	
$P_{GM}$	$T_{VJ} = T_{VJM}$	$t_p = 30\mu\text{s}$ 10      W
	$I_T = I_{TAVM}$	$t_p = 300\mu\text{s}$ 5      W
$P_{GAVM}$		0.5      W
$V_{RGM}$		10      V
$T_{VJ}$		-40...+125      °C
$T_{VJM}$		125      °C
$T_{stg}$		-40...+125      °C
$V_{ISOL}$	50/60 HZ, RMS	$t = 1 \text{ min}$ 2500      V~
	$I_{ISOL} \leq 1 \text{ mA}$	$t = 1 \text{ s}$ 3000      V~
$M_d$	Mounting torque	(M6) 5      Nm
	Terminal connection torque	(M6) 5      Nm
Weight	typ.	270      g



Characteristic picture

#### Features

- Package with screw terminals
- Isolation voltage 3000V~
- Planar glasspassivated chips
- UL registered, E 148688

#### Applications

- Heat and temperature control for industrial furnaces and chemical processes
- Lighting control
- Motor control
- Power converter

#### Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- High power density

Symbol	Test Conditions	Characteristic Values	
$I_D, I_R$	$T_{VJ} = T_{VJM}; V_R = V_{RRM}; V_D = V_{DRM}$	$\leq 5$ mA	
$V_T$	$I_T = 300A; T_{VJ} = 25^\circ C$	$\leq 1.74$ V	
$V_{TO}$	For power-loss calculations only ( $T_{VJ}=T_{VJmax}$ )	0.85 V	
$r_T$		3.2 m $\Omega$	
$V_{GT}$	$V_D = 6V$	$T_{VJ} = 25^\circ C$	$\leq 2.5$ V
		$T_{VJ} = -40^\circ C$	$\leq 2.6$ V
$I_{GT}$	$V_D = 6V$	$T_{VJ} = 25^\circ C$	$\leq 150$ mA
		$T_{VJ} = -40^\circ C$	$\leq 200$ mA
$V_{GD}$	$T_{VJ} = T_{VJM}$	$V_D = 2/3 V_{DRM}$	$\leq 0.2$ V
$I_{GD}$			$\leq 10$ mA
$I_L$	$T_{VJ} = 25^\circ C; t_p = 10\mu s$	$\leq 450$ mA	
	$I_G = 0.45A; di_G/dt = 0.45 A/\mu s$		
$I_H$	$T_{VJ} = 25^\circ C; V_D = 6V; R_{GK} = \infty$	$\leq 200$ mA	
$t_{gd}$	$T_{VJ} = 25^\circ C; V_D = 1/2 V_{DRM}$	$\leq 2$ $\mu s$	
	$I_G = 0.45A; di_G/dt = 0.45A/\mu s$		
$t_q$	$T_{VJ} = T_{VJM}; I_T = 150A, t_p = 200\mu s; -di/dt=10A/\mu s$	185 $\mu s$	
	$V_R = 100V; dv/dt = 20 V/\mu s; V_D = 2/3 V_{DRM}$		
$R_{thJC}$	per thyristor; sine 180°el	0.3 K/W	
	per bridge	0.1 K/W	
$R_{thJK}$	per thyristor; sine 180°el	0.5 K/W	
	per bridge	0.167 K/W	
$d_s$	Creeping distance on surface	10 mm	
$d_A$	Creeping distance in air	9.4 mm	
$a$	max. allowable acceleration	50 m/s <sup>2</sup>	

## Package, style and outline

Dimensions in mm (1 mm=0.0394")

